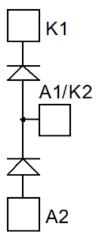
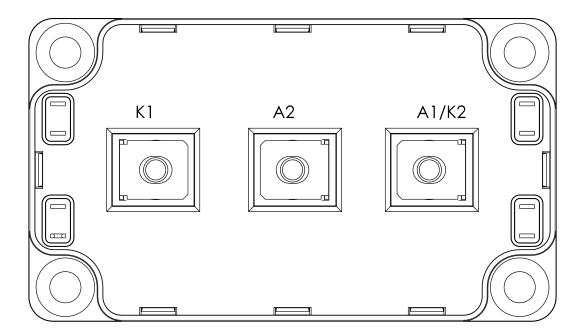


# **MSCDC300A120AG SiC Diode Phase Leg Power Module**

## 1 Product Overview

This section provides the product overview for the MSCDC300A120AG device.





All ratings at  $T_i$  = 25 °C, unless otherwise specified.

**Caution:** These devices are sensitive to electrostatic discharge. Proper handling procedures should be followed.



#### 1.1 Features

The following are key features of the MSCDC300A120AG device:

- Silicon carbide (SiC) Schottky diode
  - Zero reverse recovery
  - Zero forward recovery
  - Temperature-independent switching behavior
  - Positive temperature coefficient on VF
- Low stray inductance
- M5 power connectors
- High level of integration
- Aluminum nitride (AIN) substrate for improved thermal performance

#### 1.2 Benefits

The following are benefits of the MSCDC300A120AG device:

- Outstanding performance at high-frequency operation
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- RoHS compliant

### 1.3 Applications

The MSCDC300A120AG device is designed for the following applications:

- Uninterruptible power supply (UPS)
- Induction heating
- Welding equipment
- High-speed rectifiers



# **2** Electrical Specifications

This section provides the electrical specifications for the MSCDC300A120AG device.

### 2.1 Absolute Maximum Ratings

The following table shows the absolute maximum ratings per diode for the MSCDC300A120AG device.

**Table 1 • Absolute Maximum Ratings** 

| Symbol           | Parameter                       |            | Maximum Ratings | Unit |
|------------------|---------------------------------|------------|-----------------|------|
| V <sub>RRM</sub> | Repetitive peak reverse voltage |            | 1200            | V    |
| lF               | DC forward current              | Tc = 90 °C | 300             | Α    |

The following table shows the thermal and package characteristics of the MSCDC300A120AG.

**Table 2 • Thermal and Package Characteristics** 

| Symbol | Characteristic   |               |    | Min | Max                   | Unit |
|--------|--|---------------|----|-----|-----------------------|------|
| Visol  | RMS isolation voltage, any terminal to case t =1 minute, 50 Hz/60 Hz |               |    |     |                       | V    |
| Тл     | Operating junction temperature range                                 |               |    | -40 | 175                   | °C   |
| Тлор   | Recommended junction temperature under switching conditions          |               |    | -40 | T <sub>Jmax</sub> -25 |      |
| Тѕтс   | Storage temperature range  |               |    | -40 | 125                   |      |
| Tc     | Operating case temperature   |               |    | -40 | 125                   |      |
| Torque | Mounting torque  | To heatsink   | M6 | 3   | 5                     | N.m  |
|        |  | For terminals | M5 | 2   | 3.5                   |      |
| Wt     | Package weight   |               |    |     | 300                   | g    |

#### **2.2** Electrical Performance

The following table shows the electrical characteristics per diode of the MSCDC300A120AG.

Table 3 • Electrical Characteristics Per Diode

| Symbol     | Characteristic  Diode forward voltage | Test Conditions                   |                         | Min | Тур  | Max   | Unit |
|------------|---------------------------------------|-----------------------------------|-------------------------|-----|------|-------|------|
| VF         |                                       | I <sub>F</sub> = 300 A            | T <sub>j</sub> = 25 °C  |     | 1.5  | 1.8   | V    |
|            |                                       |                                   | T <sub>j</sub> = 175 °C |     | 2.1  |       | -    |
| Ігм        | Reverse leakage current               | V <sub>R</sub> = 1200 V           | T <sub>j</sub> = 25 °C  |     | 0.09 | 1.2   | mA   |
|            |                                       |                                   | T <sub>j</sub> = 175 °C |     | 1.5  |       | _    |
| <b>Q</b> c | Total capacitive charge               | V <sub>R</sub> = 600 V            |                         |     | 1344 |       | nC   |
| С          | Total capacitance                     | f = 1 MHz, V <sub>R</sub> = 400 V |                         |     | 1476 |       | pF   |
|            |                                       | f = 1 MHz, V <sub>R</sub> = 3     | 800 V                   |     | 1092 |       | =    |
| RthJC      | Junction-to-case thermal resistance   |                                   |                         |     |      | 0.109 | °C/W |



## 2.3 Performance Curves

This section shows the typical performance curves for the MSCDC300A120AG device.

Figure 1 • Maximum Transient Thermal Impedance

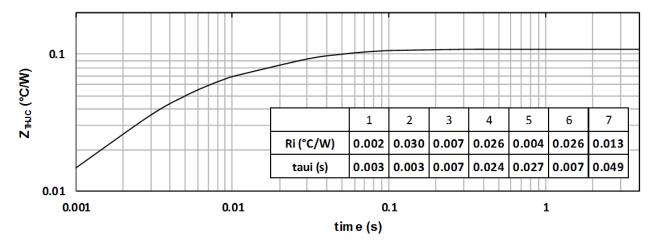


Figure 2 • Forward Current vs. Forward Voltage

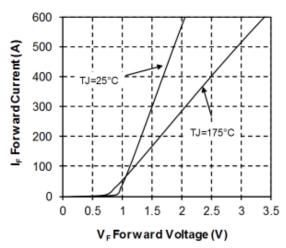
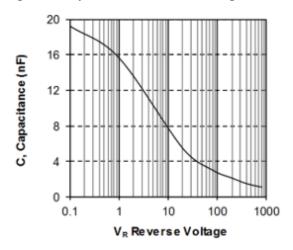


Figure 3 • Capacitance vs. Reverse Voltage





# **3** Package Specifications

This section shows the package specifications for the MSCDC300A120AG device.

## 3.1 Package Outline Drawing

The following drawing shows the package outline of the MSCDC300A120AG device. The dimensions in the following figure are in millimeters.

Figure 4 • Package Outline Drawing

